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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**APPLICANT:** Martin Czech et al.

**GROUP:** 2811

**SERIAL NO:** 09/780,976

**EXAMINER:** Steven Lok

**FILED:** February 9, 2001

**FOR:** LATERAL THYRISTOR STRUCTURE FOR PROTECTION  
AGAINST ELECTROSTATIC DISCHARGE

Honorable Commissioner of Patents  
and Trademarks  
Washington, D.C. 20231

Sir:

**AMENDMENT**

This amendment is in response to the Official Action dated June 18, 2002.

Please amend the application as follows:

IN THE CLAIMS:

✓  
Cancel claim 7.

Amend claims 1-3, 6 and 8-12 as follows:

Sub  
B2  
1. (amended) A lateral thyristor structure for protection against electrostatic discharge,  
comprising:

at least two lateral thyristors, which each include

a semiconductor substrate of a first conduction type, with a surface;

a well region of a second conduction type, opposite to said first conduction type,

which is introduced into said surface of said semiconductor substrate;